

- 20 W Pulsed Power Dissipation
- 100 V Capability
- 2 A Continuous Collector Current
- 4 A Peak Collector Current

LP PACKAGE
(TOP VIEW)

MDTRAB

absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING	SYMBOL	VALUE	UNIT
Collector-base voltage ($I_E = 0$)	V_{CBO}	60 80 100	V
Collector-emitter voltage ($I_B = 0$)	V_{CEO}	60 80 100	V
Emitter-base voltage	V_{EBO}	5	V
Continuous collector current	I_C	2	A
Peak collector current (see Note 1)	I_{CM}	4	A
Continuous base current	I_B	50	mA
Continuous device dissipation at (or below) 25°C case temperature (see Note 2)	P_{tot}	0.8	W
Pulsed power dissipation (see Note 3)	P_T	20	W
Operating junction temperature range	T_j	-55 to +150	°C
Storage temperature range	T_{stg}	-55 to +150	°C
Lead temperature 3.2 mm from case for 10 seconds	T_L	260	°C

NOTES: 1. This value applies for $t_p \leq 0.3$ ms, duty cycle $\leq 10\%$.
 2. Derate linearly to 150°C case temperature at the rate of 0.32 W/°C.
 3. $V_{CE} = 20$ V, $I_C = 1$ A, $P_W = 10$ ms, duty cycle $\leq 2\%$.

PRODUCT INFORMATION

electrical characteristics at 25°C case temperature

PARAMETER	TEST CONDITIONS			MIN	TYP	MAX	UNIT
$V_{(BR)CEO}$ Collector-emitter breakdown voltage	$I_C = 10 \text{ mA}$ (see Note 4)	$I_B = 0$	TIPP110 TIPP111 TIPP112	60 80 100			V
I_{CEO} Collector-emitter cut-off current	$V_{CE} = 30 \text{ V}$ $V_{CE} = 40 \text{ V}$ $V_{CE} = 50 \text{ V}$	$V_{BE} = 0$ $V_{BE} = 0$ $V_{BE} = 0$	TIPP110 TIPP111 TIPP112			2 2 2	mA
I_{CBO} Collector-base cut-off current	$V_{CE} = 60 \text{ V}$ $V_{CE} = 80 \text{ V}$ $V_{CE} = 100 \text{ V}$	$I_B = 0$ $I_B = 0$ $I_B = 0$	TIPP110 TIPP111 TIPP112			1 1 1	mA
I_{EBO} Emitter cut-off current	$V_{EB} = 5 \text{ V}$	$I_C = 0$				2	mA
h_{FE} Forward current transfer ratio	$V_{CE} = 4 \text{ V}$ $V_{CE} = 4 \text{ V}$	$I_C = 1 \text{ A}$ $I_C = 2 \text{ A}$	(see Notes 4 and 5)	1000 500			
$V_{CE(sat)}$ Collector-emitter saturation voltage	$I_B = 8 \text{ mA}$	$I_C = 2 \text{ A}$	(see Notes 4 and 5)			2.5	V
V_{BE} Base-emitter voltage	$V_{CE} = 4 \text{ V}$	$I_C = 2 \text{ A}$	(see Notes 4 and 5)			2.8	V
V_{EC} Parallel diode forward voltage	$I_E = 4 \text{ A}$	$I_B = 0$	(see Notes 4 and 5)			3.5	V

NOTES: 4. These parameters must be measured using pulse techniques, $t_p = 300 \mu\text{s}$, duty cycle $\leq 2\%$.

5. These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts and located within 3.2 mm from device body.

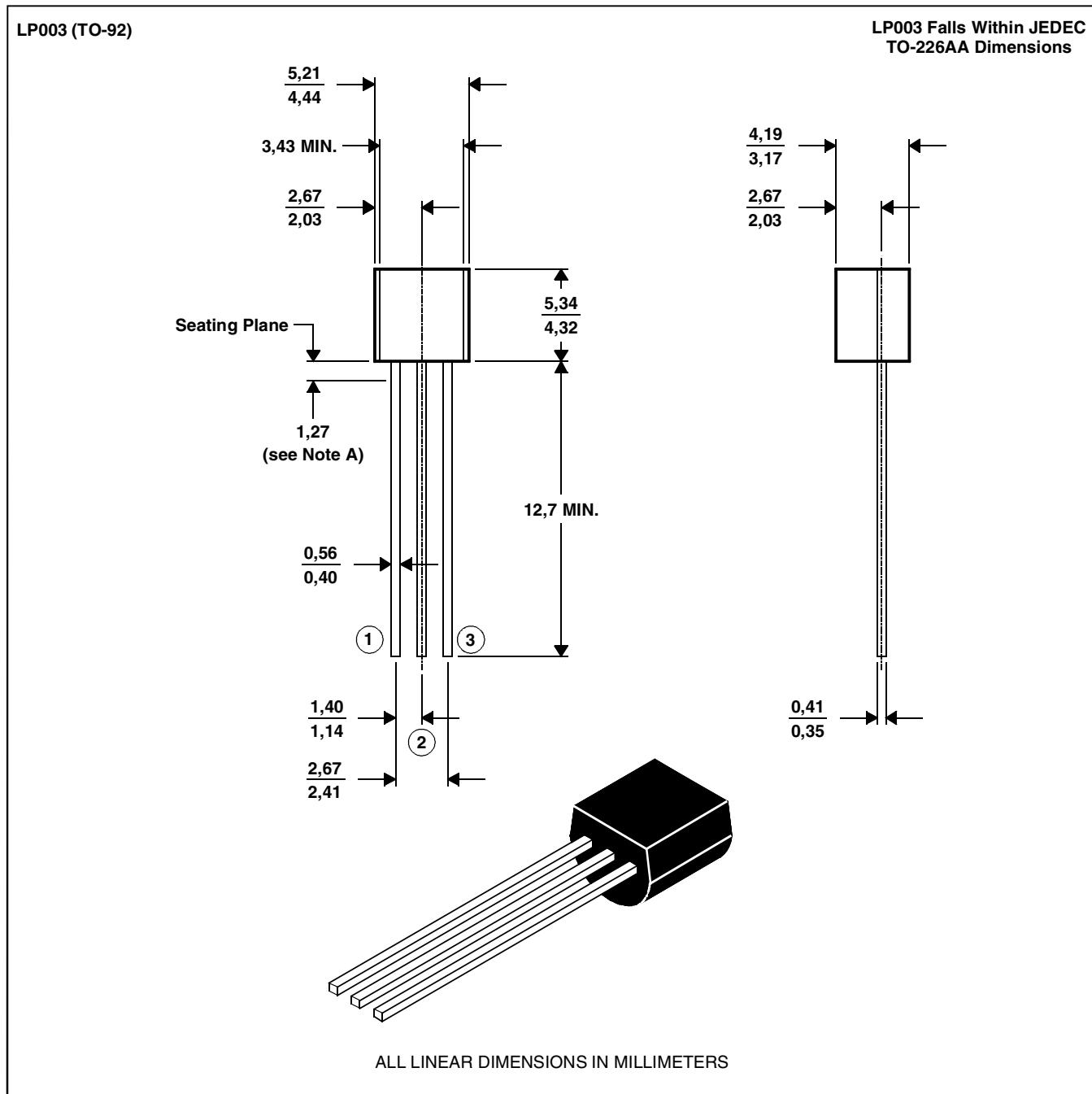
PRODUCT INFORMATION

MECHANICAL DATA

LP003 (TO-92)

3-pin cylindrical plastic package

This single-in-line package consists of a circuit mounted on a lead frame and encapsulated within a plastic compound. The compound will withstand soldering temperature with no deformation, and circuit performance characteristics will remain stable when operated in high humidity conditions. Leads require no additional cleaning or processing when used in soldered assembly.



NOTE A: Lead dimensions are not controlled in this area.

MDXXAX

PRODUCT INFORMATION

MAY 1989 - REVISED SEPTEMBER 2002
Specifications are subject to change without notice.

MECHANICAL DATA

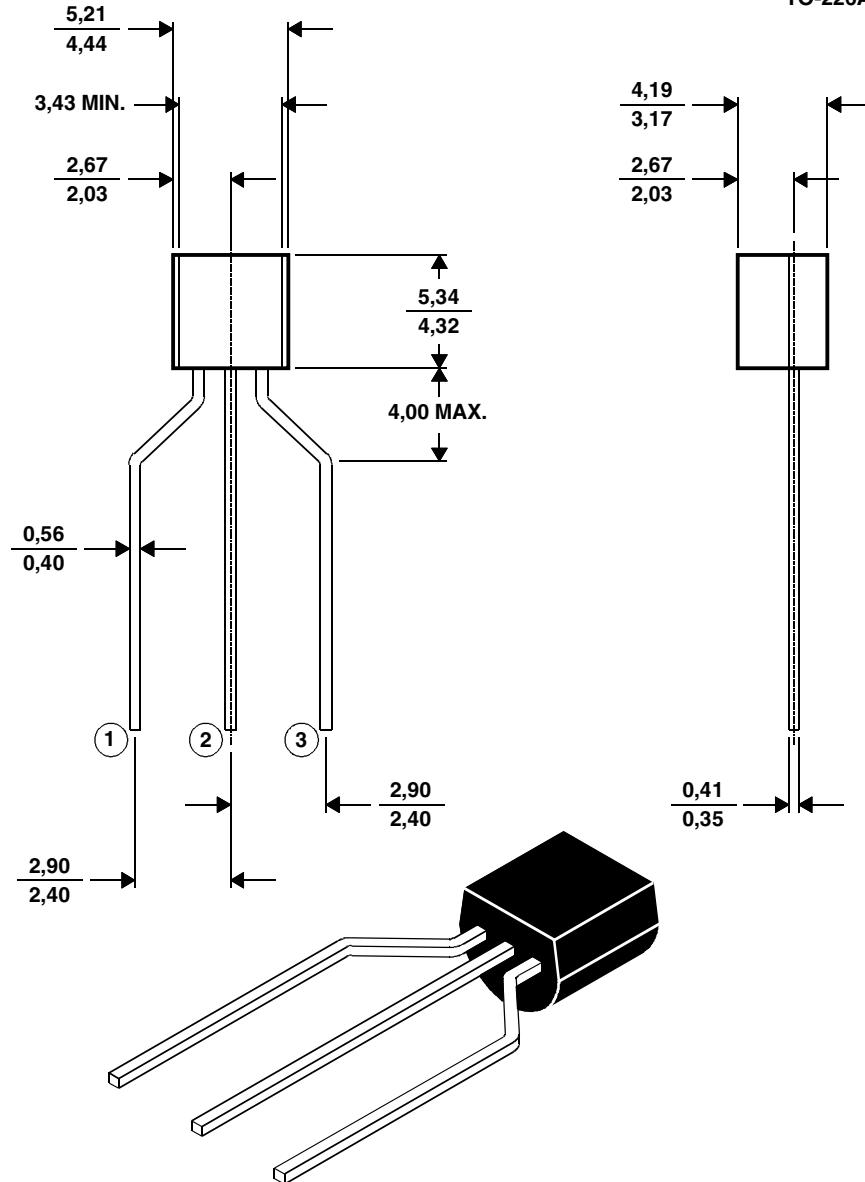
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LP003 (TO-92) - Formed Leads Version

**LP003 Falls Within JEDEC
TO-226AA Dimensions**



ALL LINEAR DIMENSIONS IN MILLIMETERS

MDXXAR

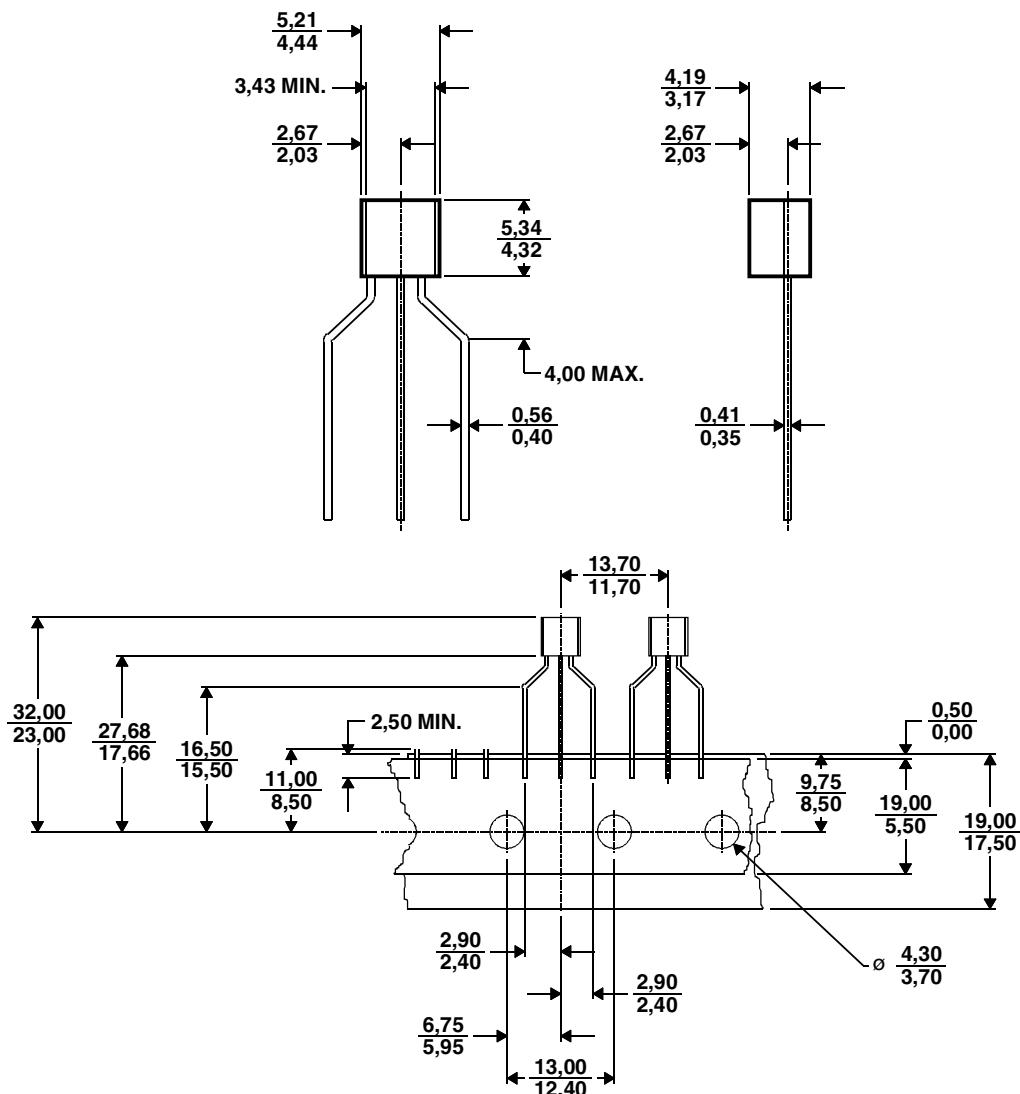
PRODUCT INFORMATION

MECHANICAL DATA

LPR

tape dimensions

LP Package (TO-92) Tape (Formed Lead Version)



ALL LINEAR DIMENSIONS IN MILLIMETERS

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PRODUCT INFORMATION

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